

RX Family

R01AN2796EJ0101

Rev.1.01 Battery Backup Function Module Firmware Integration Technology

Introduction

This application note describes a battery backup function module that uses Firmware Integration Technology (FIT).

This module reports to the user whether or not a voltage drop has occurred in either the battery backup supply voltage or the VBATT pin voltage. Based on the content reported, the user can determine whether or not the value of the real-time clock can be guaranteed, and whether or not the VBATT pin voltage has fallen.

This module is referred to as the battery backup function FIT module in the remainder of this document.

Target Device

- RX230 Group
- RX231 Group

When using this application note with other Renesas MCUs, careful evaluation is recommended after making modifications to comply with the alternate MCU.

Related Documents

- Firmware Integration Technology User's Manual (R01AN1833EU)
- RX Family Board Support Package Module Using Firmware Integration Technology (R01AN1685EU)
- RX Family Adding Firmware Integration Technology Modules to Projects (R01AN1723EU)
- RX Family Adding Firmware Integration Technology Modules to CS+ Projects (R01AN1826EJ)

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1. Overview

When this module is used, the VBATT pin voltage drop detection function can be set up and the state of the battery backup function can be read out. Furthermore, the following four states can be recognized using callback function arguments.

- (1) No battery backup supply voltage drop detected
- (2) Battery backup supply voltage drop detected
- (3) A nonmaskable interrupt due to VBATT pin voltage drop detection occurred
- (4) A maskable interrupt due to VBATT pin voltage drop detection occurred

Restrictions on this Module

- The VBATT pin must be connected to a power supply independent from VCC.
- The voltage monitoring function 0 reset should be enabled and the voltage detection level for voltage detection 0 circuit should be set. (This is 2.51 V for RX231 Group microcontrollers.)

1.1 The Battery Backup Function FIT Module

This module is embedded in projects as an API. See section 2.10, FIT Module Addition Methods, for embedding this module.

1.2 API Overview

Table 1.1 lists the API functions provided by this module. Also, table 1.2 lists the memory sizes required by this module.

Table 1.1 API Functions	
Function	Function description
R_VBATT_Open()	Sets the VBATT pin voltage drop detection enabled/disabled state and the detection level and sets up the interrupt according to the configuration option settings. After that, it discriminates whether or not a battery backup supply voltage drop has occurred and calls the callback function.
R_VBATT_Control()	Sets the VBATT pin voltage drop detection enabled/disabled state and the detection level and sets up the interrupt according to the settings specified in the arguments.
R_VBATT_GetStatus()	Acquires the status of the battery backup function.
R_VBATT_GetVersion()	Returns the version number of this module.

Table 1.1 API Functions

Table 1.2 Required Memory Sizes

Memory	Size	Remarks	
ROM	588 bytes		
RAM	4 bytes		
Maximum user stack usage	52 bytes		
Maximum interrupt stack usage	44 bytes		

Note: The configuration specifies the defaults as also the values when an RX231 Group microcontroller is used.

Note that the required memory sizes may differ with the C compiler used and the compiler options specified.

1.3 Battery Backup Function FIT Module Overview

1.3.1 API Function Specifications

When the R_VBATT_Open() function is called, it checks whether or not the voltage monitoring 0 settings are correct and whether or not a callback function was specified and if there is a problem, it returns an error and terminates function execution. If the argument settings are valid, it sets up the VBATT pin voltage drop detection function according to the settings in the configuration file (r_vbatt_rx_config.h) configuration options. After that it checks if the battery backup voltages (the VCC and VBATT pins) have fallen (the VBATTSR register VBATRLVDETF bits) and performs the following processing according to that result.

If a battery backup voltage drop has been detected, it calls the callback function with VBATT_DROP_VOLTAGE as the argument. After calling the callback function, it sets the battery backup voltage drop detection flag to 0 (battery backup voltage drop not detected).

If no battery backup voltage drop was detected, it calls the callback function with VBATT_NOT_DROP_VOLTAGE as the argument.

Figure 1.1 shows the flowchart of the R_VBATT_Open() function.

See section 2.6, Compile Time Settings, and section 2.9, Callback Functions, for details on the configuration file options and macro definitions used as callback function arguments.



RX Family

Battery Backup Function Module Firmware Integration Technology

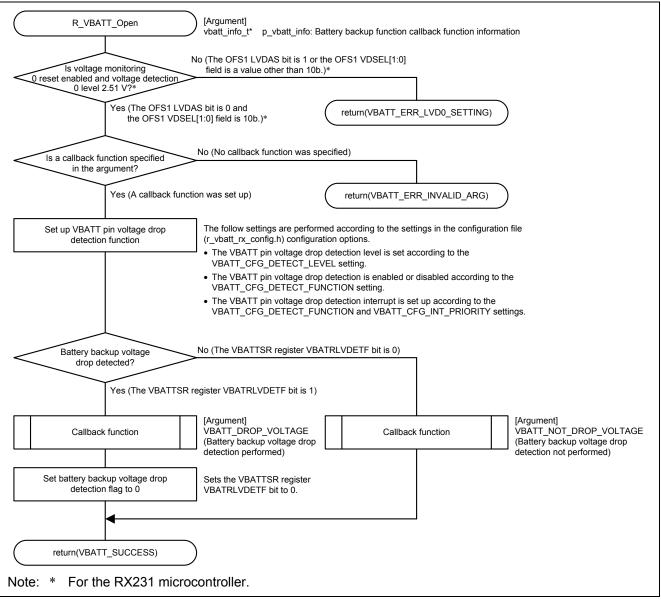


Figure 1.1 R_VBATT_Open() Function Flowchart



When the R_VBATT_Control() function is called, it checks whether or not the argument values are correct and, and if there is a problem, it returns an error and terminates function execution. If the argument settings are valid, it sets the VBATT pin voltage drop detection function enabled/disabled state and the detection level, and it sets up the interrupt, according to the values set in the arguments.

Figure 1.2 shows the flowchart of the R_VBATT_Control() function.

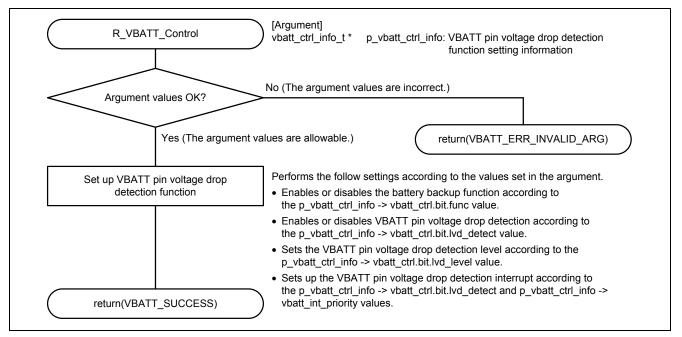


Figure 1.2 R_VBATT_Control() Function Flowchart

When the R_VBATT_GetStatus() function is called, it determines if VBATT pin voltage drop detection is enabled and if whether or not the argument values are correct and, and if there is a problem, it returns an error and terminates function execution. If the argument settings are valid, it reads out the value of the VBATT status register (VBATTSR). The read out value is stored at the address received as an argument.

Figure 1.3 shows the flowchart of the R_VBATT_GetStatus() function.

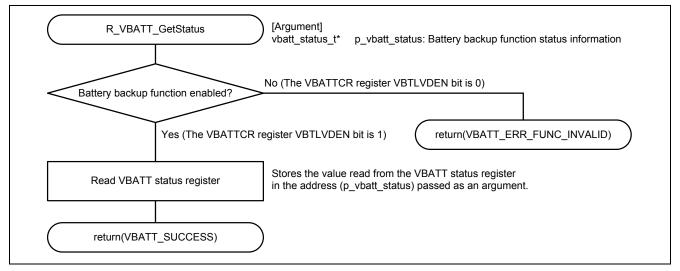
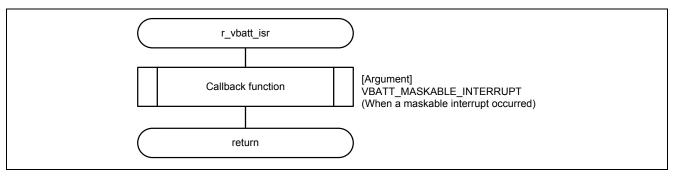


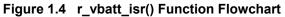
Figure 1.3 R_VBATT_GetStatus() Function Flowchart

1.3.2 Interrupt Specifications

When the interrupt used when a VBATT pin voltage drop is set to be a maskable interrupt, when this maskable interrupt occurs, the callback function is called with VBATT_MASKABLE_INTERRUPT as the argument.

Figure 1.4 shows the flowchart of the r_vbatt_isr() function.





When the interrupt used when a VBATT pin voltage drop is set to be a nonmaskable interrupt, when this nonmaskable interrupt occurs, the callback function is called with VBATT_NON_MASKABLE_INTERRUPT as the argument.

Figure 1.5 shows the flowchart of the r_vbatt_nmi_isr() function.

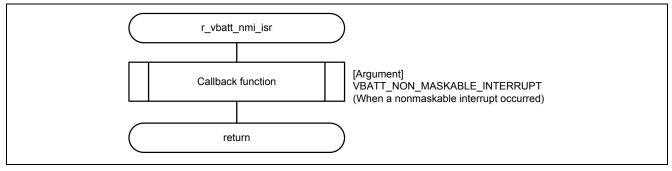


Figure 1.5 r_vbatt_nmi_isr() Function Flowchart



1.4 Usage Example

Call the R_VBATT_Open() function immediately after the reset start. The callback function should perform processing based on the value of its arguments.

Table 1.3 lists the callback function's arguments and processing that should be performed, and figure 1.6 shows a usage example of the battery backup function FIT module.

Table 1.3 Callback Function's Arguments and Processing that Should be Performed

Argument	VBATT_NOT_DROP_VOLTAGE	VBATT_DROP_VOLTAGE	VBATT_MASKABLE_INTERRUPT
	(Battery backup voltage drop	(Battery backup voltage drop	VBATT_NON_MASKABLE_INTERRUPT
	detection not performed)	detection performed)	(VBATT pin voltage drop detection interrupt)
Processing that	Reset the RAM and RTC registers	The real-time clock must be	Operations such as displaying a warning
Should be	as required.	initialized.	that the external battery level is low and
Performed			backing up data should be performed.
Reason	When the battery backup supply	When the battery backup	This interrupt occurs when the supply
	voltage has not dropped, the value	supply voltage drops, the	voltage on the VBATT pin falls. Processing
	of the RTC register will be saved,	real-time clock registers and	to handle the situation where the VBATT pin
	but RAM and the RTC interrupt	RAM go to their values after	supply voltage has fallen can be performed.
	registers will be set to their post-	a reset. Therefore	
	reset values. Therefore, the RAM	initialization is required.	
	and RTC interrupt register values		
	must be set again.		

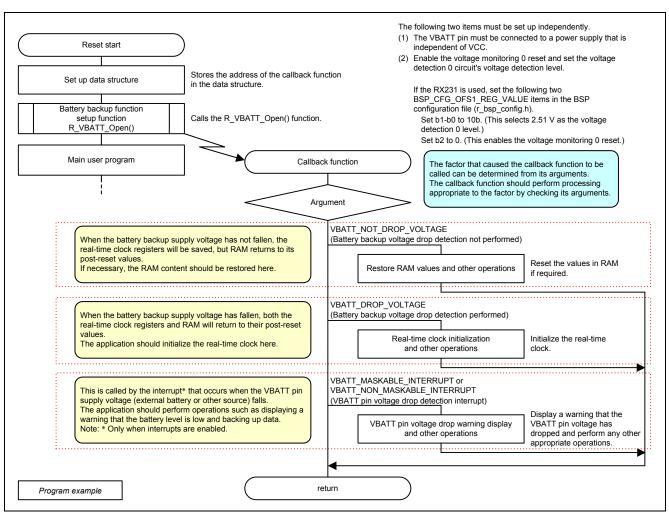


Figure 1.6 Usage Example of the Battery Backup Function FIT Module



2. API Information

The sample code provided with this application note has been confirmed to operate under the following conditions.

2.1 Hardware Requirements

The microcontroller used must support the following function.

• Battery backup function

2.2 Software Requirements

This driver depends on the following packages.

• r_bsp

2.3 Supported Tool Chain

This driver has been confirmed to operate under the following tool chain.

• Renesas RX Toolchain v.2.03.00 (RX231, RX230)

2.4 Header Files

All the AP calls and the interface definitions required to support those calls are coded in the file r_vbatt_rx_if.h.

2.5 Integer Types

This project is coded in ANSI C99. These types are defined in stdint.h.



2.6 Compile Time Settings

This module configuration options are set in r_vbatt_rx_config.h.

The table below lists the option names and set values.

Configuration options in r_vbatt_rx_config.h		
#define VBATT_CFG_DETECT_FUNCTION Note: The default value is "VBATT_DTCT_DISABLE"	Selects whether or not the VBATT pin voltage drop detection function is used. This also selects the interrupt generated when a voltage drop is detected. For VBATT_DTCT_DISABLE: The VBATT pin voltage drop detection function is set to invalid and the interrupt is disabled. For VBATT_DTCT_ENABLE_INT_DISABLE: The VBATT pin voltage drop detection function is enabled and the interrupt is disabled. For VBATT_DTCT_ENABLE_NMI_ENABLE: The VBATT_DTCT_ENABLE_NMI_ENABLE: The VBATT_pin voltage drop detection function is enabled and the nonmaskable interrupt is enabled as the interrupt. For VBATT_DTCT_ENABLE_INT_ENABLE:	
#define VBATT_CFG_DETECT_LEVEL Note: The default value is	The VBATT pin voltage drop detection function is enabled and the maskable interrupt is enabled as the interrupt. The VBATT pin voltage drop detection level can be selected. For VBATT DTCT LEVEL 2 20 V, the detection level is	
"VBATT_DTCT_LEVEL_2_20_V"	For VBATT_DTCT_LEVEL_2_20_V, the detection level is set to 2.20 V. For VBATT_DTCT_LEVEL_2_00_V, the detection level is set to 2.00 V.	
#define VBATT_CFG_INT_PRIORITY Note: The default value is "5"	The interrupt priority level can be selected when a maskable interrupt is used as the VBATT pin voltage drop detection interrupt. The value selected by a value from 1 to 15 is set as the interrupt level. Note: This setting is only valid when VBATT_DTCT_ENABLE_INT_ENABLE is selected by VBATT_CFG_DETECT_FUNCTION.	



2.7 Arguments

This section presents the structures used as arguments to the API functions. These structures are included in the file r_vbatt_rx_if.h along with the API function prototype declarations. /* Battery backup function data structure */ typedef volatile struct { vbatt callback t callbackfunc; /* Callback function */ } vbatt info t; /* Structure used to set up the VBATT pin voltage drop detection function again */ typedef volatile struct { uint8_t rsv2; /* Reserved area */ uint8_t rsv1; /* Reserved area */ uint8_t vbatt_int_priority; /* Interrupt priority level for the VBATT pin voltage drop detection interrupt (maskable interrupt) */ union { uint8 t byte; struct { uint8 t rsv:3; /* Reserved area */ uint8 t lvd level:2; /* VBATT pin voltage drop detection level */ uint8 t lvd detect:2;/* VBATT pin voltage drop detection function */ uint8 t func:1; /* Enabled/disabled state of the battery backup function */ } bit; } vbatt ctrl; } vbatt ctrl info t; /* Structure used to hold the state of the battery backup function */ typedef volatile struct { union { uint8 t byte; struct { uint8_t rsv:6; /* Reserved area */ uint8_t vbatt_mon:1; /* VBATT pin voltage monitor flag */ uint8_t pwr_drp_dtct:1; /* Battery backup supply voltage drop detection flag */ } bit; } vbatt status; } vbatt status t;

2.8 Return Values

This section presents the return values from the API functions. This enumeration type is defined in the file r_vbatt_rx_if.h along with the API function prototype declarations.

```
/* Return value used for calls to battery backup
typedef enum
                              API functions */
{
   VBATT SUCCESS,
                           /* Processing completed without problem */
  VBATT ERR LOCK FUNC,
                           /* The function was called multiple times */
                               (Not implemented)
  VBATT ERR LVD0 SETTING, /* Illegal voltage monitoring 0 settings in
                              option function selection register 1 (OFS1) */
                           /* Invalid argument */
  VBATT ERR INVALID ARG,
  VBATT ERR FUNC INVALID, /* R VBATT GetStatus() was called when VBATT pin
                              voltage drop detection was invalid */
  VBATT_ERR OTHER
                           /* Other error */
} vbatt return t;
```

2.9 Callback Function

In this module, a callback function is called when the R_VBATT_Open() function is called or when an interrupt occurs. The callback function takes an argument whose set value determines whether a battery backup voltage drop was detected, or whether it was called from an interrupt handler when the VBATT pin voltage fell.

Table 2.1 lists the constant definitions (enum vbatt_cb_evt_t) for the argument passed to the callback function.

For callback function setup, the address of the callback function to be registered should be stored in "callbackfunc" member in the structure described in section 2.7, Arguments.

Table 2.1	Definitions of Constants Passed as an Argument to the Callback Function
	(enum vbatt_cb_evt_t)

Defined Constant	Conditions for Passing as an Argument
VBATT_NOT_DROP_VOLTAGE	When R_VBATT_Open() was called in the state where a
	battery backup supply voltage drop was not detected
	(the VBATTSR register VBATRLVDETF bit was 0)
VBATT_DROP_VOLTAGE	When R_VBATT_Open() was called in the state where a
	battery backup supply voltage drop was detected
	(the VBATTSR register VBATRLVDETF bit was 1)
VBATT_MASKABLE_INTERRUPT	When a maskable interrupt due to a voltage drop on the
	VBATT pin occurred
VBATT_NON_MASKABLE_INTERRUPT	When a nonmaskable interrupt due to a voltage drop on the
	VBATT pin occurred



2.10 Fit Module Addition Methods

This module must be added to each project used in e² studio.

There are two methods for adding to a project: using the FIT plug-in and adding manually.

When the FIT plug-in is used, FIT modules can be added to projects easily and the include file path will be updated automatically. Therefore we recommend using the FIT plug-in when adding FIT modules to a project.

For details on the method for addition FIT modules using the FIT plug-in, see section 2., Adding FIT Modules to e² studio Projects Using FIT Plug-In, in the "Adding Firmware Integration Technology Modules to Projects (R01AN1723EU)" application note.

See section 3, Adding FIT Modules to e^2 studio Projects Manually, for adding the FIT module by hand without using the FIT plugin.

When this FIT module is used, the Board Support Package FIT module (BSP module) must also be added to the project. See the Board Support Package Module Using Firmware Integration Technology (R01AN1685EU) application note for the methods for adding the BSP module.



3. API Functions

3.1 R_VBATT_Open()

This function sets up the VBATT pin voltage drop detection function and determines whether or not the battery backup supply voltage has fallen.

This function is called once and only once after a reset start. The processing performed when a drop in the battery backup supply voltage is detected and when no drop is detected are performed by a callback function called by this function.

Format

```
vbatt_return_t R_VBATT_Open (
    vbatt_info_t *    p_vbatt_info
)
```

Parameters

p_vbatt_info

Pointer to a data structure for the battery backup information. The following members are used by this function. See section 2.7, Arguments, for details on this structure.

vbatt_callback_t callbackfunc; /* Address of the callback function */

Return Values

```
VBATT_SUCCESS /* Processing completed without problem */
VBATT_ERR_LVD0_SETTING /* Illegal voltage monitoring 0 settings in
option function selection register 1 (OFS1) */
VBATT_ERR_INVALID_ARG /* Invalid argument */
```

Properties

A prototype declaration for this function appears in r_vbatt_rx_if.h.

Description

This function sets the enabled or disabled state of the VBATT pin voltage drop detection function, the detection level, and the interrupts according to settings in the configuration options. After that, it determines whether or not the battery backup supply voltage has dropped and calls the callback function.

When calling the callback function:

- If a battery backup supply voltage drop has not been detected: A pointer to a variable that has been set to VBATT_NOT_DROP_VOLTAGE is passed as an argument.
- If a battery backup supply voltage drop has been detected: A pointer to a variable that has been set to VBATT_DROP_VOLTAGE is passed as an argument.

Reentrant

This function is not reentrant.



Example

```
#include "r_vbatt_rx_if.h"
void vbatt_callback(vbatt_cb_evt_t * vbatt_cb_event);
void main(void)
{
 vbatt return t
                   ret;
 vbatt info t vbatt info;
 vbatt info.callbackfunc = vbatt callback;
 ret = R VBATT Open(&vbatt info);
 if (VBATT SUCCESS != ret)
 {
   /* Please do the processing at the time of the error */
 }
 while(1);
}
void vbatt callback(vbatt cb evt t * vbatt cb event)
{
 switch(*vbatt cb event)
 {
  /* Battery backup power voltage drop not detected */
  case VBATT NOT DROP VOLTAGE:
      /* Please set RAM again as needed */
  break;
   /* Battery backup power voltage drop detected */
  case VBATT DROP VOLTAGE:
      /* Please initialize the Realtime Clock */
  break;
   /* VBATT voltage drop detected interrupt */
  case VBATT MASKABLE INTERRUPT:
  case VBATT NON MASKABLE INTERRUPT:
      /* Please process warning indication, backup, etc. */
  break;
  default:
     /* Do nothing */
  break;
 }
}
```

Special Notes None



3.2 R_VBATT_Control()

This function sets the enabled or disabled state of the battery backup function and sets up the VBATT pin voltage drop detection function. This function is used when changing the content of these settings from those made with the $R_VBATT_Open()$ function.

Format

```
vbatt_return_t R_VBATT_Control (
   vbatt_ctrl_info_t * p_vbatt_ctrl_info
)
```

Parameters

p_vbatt_ctrl_info

Pointer to the data structure used by the VBATT pin voltage drop detection function. The following members are used by this function. See section 2.7, Arguments, for details on this structure.

```
typedef volatile struct
{
 uint8_trsv2; /* Reserved area */
uint8_trsv1; /* Reserved area */
uint8_tvbatt_int_priority; /* Interrupt priority level for
                                      the VBATT pin voltage drop detection
                                       interrupt (maskable interrupt) */
 union
 {
   uint8 t
               byte;
   struct
   {
      uint8_t rsv:3; /* Reserved area */
uint8_t lvd_level:2; /* VBATT pin voltage drop detection level */
      uint8_t lvd_detect:2; /* VBATT pin voltage drop detection function */
      uint8_t func:1; /* Enabled/disabled state of the battery backup
                                       function */
   } bit;
 } vbatt ctrl;
} vbatt ctrl info t;
```

Return Values

VBATT_SUCCESS/* Processing completed without problem */VBATT_ERR_INVALID_ARG/* Invalid argument */

Properties

A prototype declaration for this function appears in r_vbatt_rx_if.h.



Description

This function sets the enabled or disabled state of the battery backup function, the enabled or disabled state of the VBATT pin voltage drop detection function, the detection level, and the interrupts according to the settings of the arguments.

Reentrant

This function is not reentrant.

Example

```
#include "r_vbatt_rx_if.h"
void main(void)
{
 vbatt return t
                       ret;
 vbatt_return_t ret;
vbatt_ctrl_info_t vbatt_ctrl_info;
 /* Battery backup function enable */
 vbatt ctrl info.vbatt ctrl.bit.func = 1;
 /* VBATT drop detect function enable and maskable interrupt enable */
 vbatt ctrl info.vbatt ctrl.bit.lvd detect = VBATT DTCT ENABLE INT ENABLE;
 /* VBATT drop detect level is 2.00V */
 vbatt ctrl info.vbatt ctrl.bit.lvd level = VBATT DTCT LEVEL 2 00 V;
 /* interrupt priority level is 7*/
 vbatt ctrl info.vbatt int priority = 7;
 ret = R VBATT Control(&vbatt ctrl info);
 if (VBATT SUCCESS != ret)
 {
      /* Please do the processing at the time of the error */
 }
 while(1);
}
```



Special Notes

The table below lists and describes the range of values the arguments may be set to and the meanings of those arguments.

Structure (vbatt_ctrl_info_t)		_		
Member	Bit	Allowable Range	Meaning	
vbatt_ctrl	func	0 to 1	The enabled or disabled state of the battery backup function	
			can be changed.	
			0: The battery backup function is disabled.	
			1: The battery backup function is enabled.	
	lvd_detect	Selected from macro definitions for the corresponding meaning	Selects whether or not the VBATT pin voltage drop detection function is used. This also selects the interrupt generated when a voltage drop is detected. For VBATT_DTCT_DISABLE:	
			The VBATT pin voltage drop detection function is set to invalid and the interrupt is disabled. For VBATT_DTCT_ENABLE_INT_DISABLE:	
			The VBATT pin voltage drop detection function is enabled and the interrupt is disabled. For VBATT_DTCT_ENABLE_NMI_ENABLE:	
			The VBATT pin voltage drop detection function is enabled and the nonmaskable interrupt is enabled as the interrupt.	
			For VBATT_DTCT_ENABLE_INT_ENABLE: The VBATT pin voltage drop detection function is enabled and the maskable interrupt is enabled as the interrupt.	
	lvd_level	Selected from macro definitions for the corresponding	The VBATT pin voltage drop detection level can be selected. For VBATT_DTCT_LEVEL_2_20_V, the detection level is set to 2.20 V.	
		meaning	For VBATT_DTCT_LEVEL_2_00_V, the detection level is set to 2.00 V.	
vbatt_int_priority		1 to 15	The interrupt priority level can be selected when a maskable interrupt is used as the VBATT pin voltage drop detection interrupt.	
			The value selected by a value from 1 to 15 is set as the interrupt level.	
			Note: This setting is only valid when VBATT_DTCT_ENABLE_INT_ENABLE is selected by Ivd_detect.	



3.3 **R VBATT GetStatus()**

This function acquires the status for the battery backup function. This function is used to check the status of the battery backup function.

Format

```
vbatt_return_t R_VBATT_GetStatus (
 vbatt_status_t *
                  p_vbatt_status
)
```

Parameters

p vbatt status

Pointer to a variable to hold the battery backup function status.

The following members are used by this function. See section 2.7, Arguments, for details on this structure.

```
typedef volatile struct
{
 union
 {
   uint8 t
                byte;
   struct
   {
      uint8_t rsv:6;  /* Reserved area */
uint8_t vbatt_mon:1;  /* VBATT pin voltage monitor flag */
      uint8 t pwr drp dtct:1; /* Battery backup supply voltage drop
                                        detection flag */
   } bit;
 } vbatt status;
} vbatt status t;
```

Return Values

```
VBATT_ERR_INVALID_ARG /* Processing completed without problem */
VBATT_ERR_INVALID_ARG /* Invalid argument */
VBATT_ERR_FUNC_INVALID /* R_VBATT_GetStatus ()
                                              /* R VBATT GetStatus() was called when VBATT pin
```

Properties

A prototype declaration for this function appears in r vbatt rx if.h.

Description

This function reads out the VBATT status register (VBATTSR) to acquire the status of the battery backup function. It then stores that information at the address passed as an argument.

Reentrant

This function is reentrant.



Example

```
#include "r_vbatt_rx_if.h"
void main(void)
{
 vbatt_return_t ret;
vbatt_status_t vbatt_status;
vbatt_ctrl_info_t vbatt_ctrl_info;
 /* VBATT drop detect function enable */
 vbatt_ctrl_info.vbatt_ctrl.bit.func = 1;
 vbatt_ctrl_info.vbatt_ctrl.bit.lvd_detect = VBATT_DTCT_ENABLE_INT_DISABLE;
 vbatt ctrl info.vbatt ctrl.bit.lvd level = VBATT DTCT LEVEL 2 20 V;
 vbatt ctrl info.vbatt int priority = 5;
 ret = R VBATT Control(&vbatt ctrl info);
 if (VBATT SUCCESS != ret)
 {
      /* Please do the processing at the time of the error */
 }
 /* gets the state of the battery backup function */
 ret = R VBATT GetStatus(&vbatt status);
 if (VBATT SUCCESS != ret)
 {
      /* Please do the processing at the time of the error */
 }
 while(1);
}
```

Special Notes

The table below shows the layout of the status flags.

Bit	b7 to b2	b1	b0	
Bit Name	Reserved area	VBATT pin voltage monitor flag	Battery backup supply voltage drop detection flag	
Symbol	rsv	vbatt_mon	pwr_drp_dtct	
Function	Undefined	 0: VBATT < Vdetvbt 1: VBATT ≥ Vdetvbt or the VBATT detection function was disabled. 	0: Battery backup supply voltage drop not detected1: Battery backup supply voltage drop detected	



3.4 **R_VBATT_GetVersion()**

This function returns the version number of the API.

Format

uint32_t R_VBATT_GetVersion(void)

Parameters

None

Return Values

Version number

Properties

A prototype declaration for this function appears in r_vbatt_rx_if.h.

Description

This function returns the version number of this API.

Reentrant

This function is reentrant.

Example

```
uint32_t version;
version = R VBATT GetVersion();
```

Special Notes

This function can be compiled in line by using the "#pragma inline" directive.



4. Sample Code

4.1 Example of Use Combined with the RTC FIT Module

This sample code shows the use of the battery backup function FIT module in combination with the RTF FIT module, which is used for real-time clock settings.

The configuration options are set as follows.

- The BSP FIT module BSP_CFG_OFS1_REG_VALUE is set to 0xFFFFFFA.
- The default values are used for the RTC FIT module and the VBATT FIT module settings.

This sample code operates in the sequence (1) to (3) shown below.

(1) The R_VBATT_Open() function is called.

(The callback function is called when the R_VBATT_Open() function is called.)

- (2) The callback function for the battery backup function sets up the RTC according to whether or not a battery backup supply voltage drop is detected. Whether or not there is a battery backup supply voltage drop is recognized from the arguments to the callback function.
 - (2-A) If the callback function argument is VBATT_NOT_DROP_VOLTAGE, the RTC FIT module is set up again using the R_RTC_Open() and R_RTC_Read() functions.
 - (2-B) If the callback function argument is VBATT_DROP_VOLTAGE, the R_RTC_Open() function is used to initialize the RTC.
- (3) In the RTC periodic interrupt callback function, the R_RTC_Read() function is used to read out the current time. The read out time is displayed on the debugging console.

<pre>#include <stdio.h> #include "r_rtc_rx_if.h" #include "r_vbatt_rx_if.h"</stdio.h></pre>	/* This is required because printf() is used for debugging display. */				
<pre>static void vbatt_callback(vbatt_cb_evt_t static void rtc_callback(void *event);</pre>	<pre>* vbatt_cb_event);</pre>				
<pre>static tm_t rtc_curr_time; /* Data struct</pre>	ure used to store the current time from the RTC. $^{\star/}$				
void main (void)					
{ vbatt_return_t ret; vbatt_info_t vbatt_info;	/* For confirming the return value from the API function. */ /* Data structure for the battery backup function */				
<pre>vbatt_info.callbackfunc = vbatt_callbackfunc</pre>	ck; /* Callback function setup */				
<pre>ret = R_VBATT_Open(&vbatt_info);</pre>	n setup and battery backup supply voltage drop determination. */				
<pre>if (VBATT_SUCCESS != ret) { while(1); }</pre>	Executing this function results in the set up callback function (vbatt_callback()) being called.				
<pre>while(1); }</pre>					
<pre>/* Battery backup function callback function */ static void vbatt_callback(vbatt_cb_evt_t * vbatt_cb_event) /</pre>					
<pre>rtc_err_t ret; rtc_init_t rtc_info;</pre>	/* For confirming the return value from the API function. */ /* RTC data structure */				

Figure 4.1 Usage Example in Combination with the RTC FIT Module (1/3)



/* Discriminate based on the argument */ switch(*vbatt cb event) { /* If no battery backup supply voltage drop is detected. $\star/$ case VBATT NOT DROP VOLTAGE: /* Set up the RTC data structure again */ rtc_info.output_freq = RTC_OUTPUT_OFF; /* Stop RTCOUT output */ rtc_info.periodic_freq = RTC_PERIODIC_1_HZ; /* RTC periodic interrupt generation period: 1 second */ /* Interrupt priority level */ rtc_info.periodic_priority = 8; rtc_info.set_time = false; /* Do not update the RTC clock counter I/O register. */ /* Callback function setup */ rtc_info.p_callback = rtc_callback; /* RTC re-setup */ ret = R RTC Open(&rtc info, &rtc curr time); Although the RTC I/O register is saved, RAM if (RTC_SUCCESS != ret) and other registers are reset. { while(1); Therefore, the RTC FIT module is setup again. } /* Read out the current time information from the RTC clock counter I/O register and store it in the data structure. */ ret = R_RTC_Read(&rtc_curr_time, NULL); if (RTC_SUCCESS != ret) Since the RTC I/O register is saved, the current { time information is read from the RTC I/O register while(1); by the R_RTC_Read() function and stored again in } the data structure. break; /* When a battery backup supply voltage drop was detected */ case VBATT DROP VOLTAGE: /* RTC data structure setup */ rtc_info.output_freq = RTC_OUTPUT_OFF; /* Stop RTCOUT output */ rtc_info.periodic_freq = RTC_PERIODIC_1_HZ; /* RTC periodic interrupt generation period: 1 second */ rtc_info.periodic_priority = 8; /* Interrupt priority level */
rtc info.set time = true; /* Update the RTC clock counter I/O register. */ /* Callback function setup */ rtc_info.p_callback = rtc_callback; /* Set the current time information structure time setting to "2015-06-30 12:34:56" */ /* Hours (0 - 23) */ rtc_curr_time.tm_hour = 12; rtc_curr_time.tm_mday = 30; rtc_curr_time.tm_mon = 6; /* Day (1 - 31) */ /* Month (0 - 11, 0 = January) */ rtc_curr_time.tm_year = 115; /* Year (referenced to 1900) */ rtc_curr_time.tm_wday = 0; /* Day of week (0 - 6, 0 = Sunday) */ rtc_curr_time.tm_yday = 0; /* Day in year (0 - 365) */ rtc_curr_time.tm_isdst = 0; /* Daylight saving time in effect (> 0), not in effect (= 0). *//* RTC initialization */ ret = R_RTC_Open(&rtc_info, &rtc_curr_time); if (RTC SUCCESS != ret) If a battery backup supply voltage drop was detected, { while(1); the microcontroller is in a state where RTC operation is not guaranteed. Therefore the RTC is reinitialized. } break; /* Interrupt due to VBATT pin voltage drop */ case VBATT_MASKABLE_INTERRUPT: case VBATT_NON_MASKABLE_INTERRUPT: /* Unused in this sample code */ break; default: /* No processing */ break; } }

Figure 4.2 Usage Example in Combination with the RTC FIT Module (2/3)



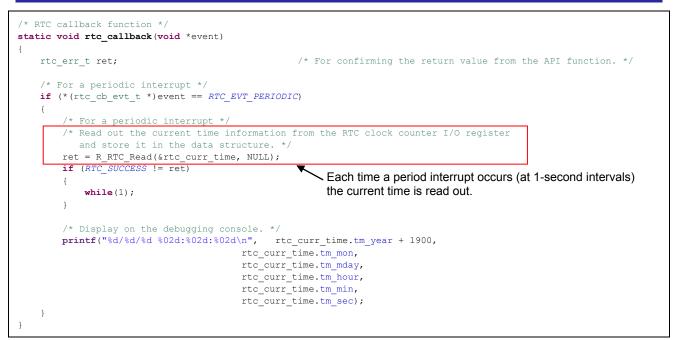


Figure 4.2 Usage Example in Combination with the RTC FIT Module (3/3)



5. Provided Modules

The provided modules can be acquired from the Renesas Electronics web site.

6. Reference Documents

User's Manual: Hardware

(The latest version can be downloaded from the Renesas Electronics website.)

Technical Update/Technical News

(The latest version can be downloaded from the Renesas Electronics website.)

User's Manual: Development Tools

RX Family C/C++ Compiler CC-RX V2.03.00 User's Manual (R20UT3248EJ) (The latest version can be downloaded from the Renesas Electronics website.)



Related Technical Updates

This module reflects the content of the following technical updates. None

Website and Support

Renesas Electronics Website <u>http://www.renesas.com/</u>

Inquiries http://www.renesas.com/contact/

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Revision History

		Description		
Rev.	Date	Page	Summary	
1.00	Aug. 24, 2015	—	First edition issued	
1.01	Aug. 31, 2015	Program	Modified the battery backup function FIT module due to the iodefine.h (V1.0C) is updated.	
			[Description] Compilations error occurs when the iodefine.h (V0.9E) is used.	
			[Workaround] Please use rev.1.01 or a later version of the battery backup function FIT module.	

General Precautions in the Handling of MPU/MCU Products

The following usage notes are applicable to all MPU/MCU products from Renesas. For detailed usage notes on the products covered by this document, refer to the relevant sections of the document as well as any technical updates that have been issued for the products.

1. Handling of Unused Pins

- Handle unused pins in accord with the directions given under Handling of Unused Pins in the manual.
- The input pins of CMOS products are generally in the high-impedance state. In operation with an unused pin in the open-circuit state, extra electromagnetic noise is induced in the vicinity of LSI, an associated shoot-through current flows internally, and malfunctions occur due to the false recognition of the pin state as an input signal become possible. Unused pins should be handled as described under Handling of Unused Pins in the manual.
- 2. Processing at Power-on
 - The state of the product is undefined at the moment when power is supplied.
 - The states of internal circuits in the LSI are indeterminate and the states of register settings and pins are undefined at the moment when power is supplied.

In a finished product where the reset signal is applied to the external reset pin, the states of pins are not guaranteed from the moment when power is supplied until the reset process is completed. In a similar way, the states of pins in a product that is reset by an on-chip power-on reset function are not guaranteed from the moment when power is supplied until the power reaches the level at which resetting has been specified.

3. Prohibition of Access to Reserved Addresses

Access to reserved addresses is prohibited.

- The reserved addresses are provided for the possible future expansion of functions. Do not access these addresses; the correct operation of LSI is not guaranteed if they are accessed.

4. Clock Signals

After applying a reset, only release the reset line after the operating clock signal has become stable. When switching the clock signal during program execution, wait until the target clock signal has stabilized.

— When the clock signal is generated with an external resonator (or from an external oscillator) during a reset, ensure that the reset line is only released after full stabilization of the clock signal. Moreover, when switching to a clock signal produced with an external resonator (or by an external oscillator) while program execution is in progress, wait until the target clock signal is stable.

5. Differences between Products

Before changing from one product to another, i.e. to a product with a different type number, confirm that the change will not lead to problems.

— The characteristics of an MPU or MCU in the same group but having a different part number may differ in terms of the internal memory capacity, layout pattern, and other factors, which can affect the ranges of electrical characteristics, such as characteristic values, operating margins, immunity to noise, and amount of radiated noise. When changing to a product with a different part number, implement a system-evaluation test for the given product.

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